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Exploring New Ultrafast Operation Regimes in Quantum Dot Lasers and Amplifiers / Cataluna, M. A.; Forrest, A.; Ribeiro, A. F.; White, S.; Krakowski, M.; Bardella, P.. - ELETTRONICO. - (2021). (Intervento presentato al convegno 2021 Conference on Lasers and Electro-Optics, CLEO 2021 tenutosi a San Jose, CA, USA nel 9-14 May 2021).

Availability:

This version is available at: 11583/2952736 since: 2022-02-02T11:06:01Z

Publisher:

Institute of Electrical and Electronics Engineers Inc.

Published

DOI:

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Exploring New Ultrafast Operation Regimes in Quantum Dot Lasers and Amplifiers

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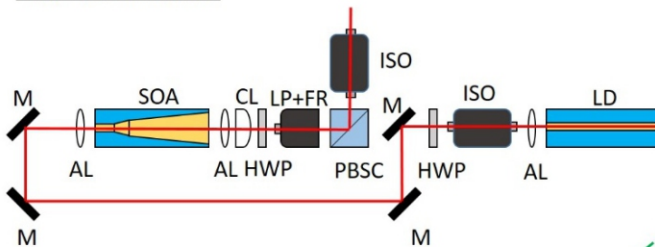
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Abstract: We will present our recent results, harnessing the flexibility of quantum dot materials towards the development of increasingly versatile regimes of ultrashort pulse generation and amplification in edge-emitting devices. © 2021 The Author(s)

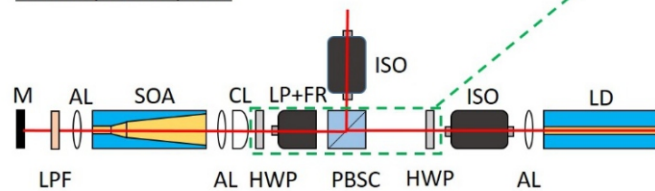
This talk will cover some of our recent research in novel operation regimes in ultrafast quantum-dot amplifiers and lasers. Quantum-dot based materials have shown a wide range of advantages for ultrafast photonic components [1,2], such as broadband gain and absorption, as well as ultrafast carrier dynamics - which by consequence underpins short absorption and gain recovery times.

We will present results showing how we have harnessed these advantages to demonstrate double-pass amplification of picosecond pulses [3], resulting in up to a 4-fold enhancement of output power with minimal increase in the pulse duration of the seed pulses, when compared to the equivalent single-pass amplification scheme (both depicted in Fig. 1). At the core of this amplification process is a two-section tapered semiconductor optical amplifier based on InAs/GaSb quantum dots. This tapered device is indeed a versatile component and its performance as a stand-alone superluminescent diode was previously reported in [4]. The same device also revealed a wide and tunable spectral asymmetry between narrow and wide facets, which was enabled by the injection of different current densities in the two sections, leading to a non-uniform filling of the confined states in the quantum dots – a phenomenon with implications for amplifiers and the setup of external cavity lasers using such devices [5]. A similar tapered device was also previously used as a building block for a high-power broadly tunable external-cavity quantum-dot laser [6]. In this talk, we will also present recent results obtained on pulse generation from quantum-dot lasers [7,8].

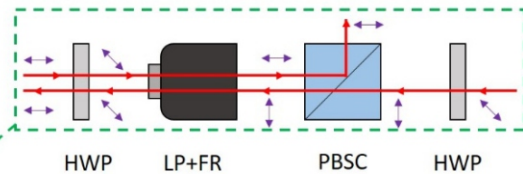
Single-pass Amplifier



Double-pass Amplifier



One-way Optical Gate



AL – Aspheric Lens
CL – Cylindrical Lens
FR – Faraday Rotator
ISO – Optical Isolator
HWP – Half Wave Plate
LD – Laser Diode
LP – Linear Polariser
LPF – Long Pass Filter
M – Mirror
PBSC – Polarising Beam Splitter Cube
SOA – Semiconductor Optical Amplifier

Fig. 1. Schematic diagrams of the single-pass and double-pass amplifier schemes. Reproduced from [3].

Acknowledgements

This project has received funding from the European Research Council (ERC) under the European Union's Horizon 2020 research and innovation program (grant agreement No 640537). The device fabrication was partly funded within the FP7 Program, via project "Fast-Dot" (grant agreement No 224338). A. F. Forrest also acknowledges prior support from an EPSRC/BBSRC PhD studentship. S.E. White also acknowledges prior support from an EPSRC/Wellcome Trust PhD studentship.

The authors would like to thank Innolume GmbH (Germany) for the growth of the QD wafers. The authors would like to thank T. Xu, M. Rossetti and I. Montrosset for stimulating discussions. From III-V Lab the authors would also like to thank M. Tran for SOA processing, Y. Robert for the SOA low-reflectivity coating, E. Vinet and M. Garcia for SOA mounting and M. Ruiz for characterization.

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